

RJP1CS04DWA / RJP1CS04DWS

1250V - 50A - IGBT

R07DS0827EJ0400

Application: Inverter

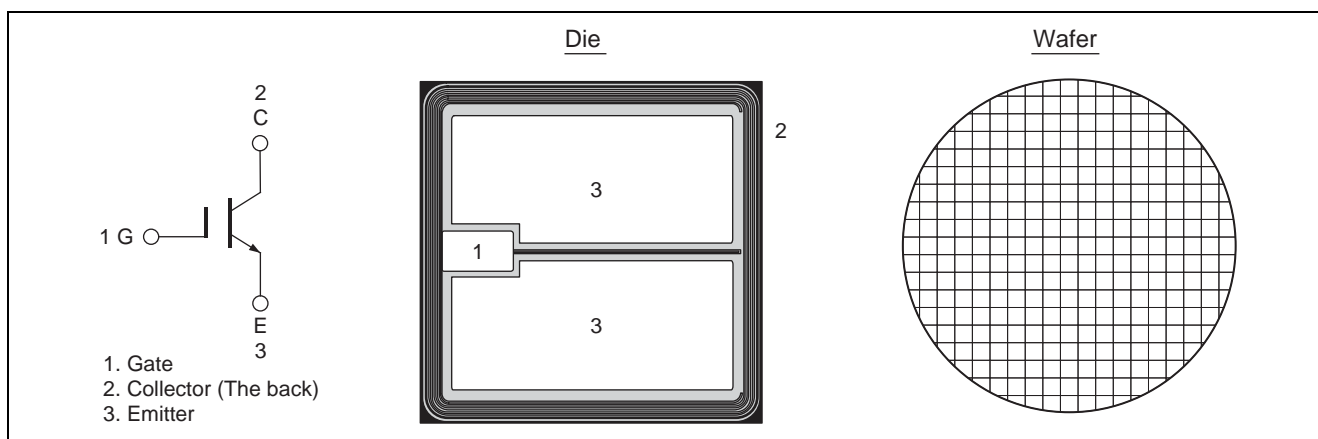
Rev.4.00

Sep 30, 2015

Features

- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.8 \text{ V typ. (at } I_C = 50 \text{ A, } V_{GE} = 15 \text{ V, } T_C = 25^\circ\text{C)}$
- High speed switching
- Short circuit withstands time (10 μs min.)

Outline



Absolute Maximum Ratings

($T_C = 25^\circ\text{C}$ unless otherwise noted)

Item	Symbol	Ratings	Unit	
Collector to emitter voltage	V_{CES}	1250	V	
Gate to emitter voltage	V_{GES}	± 30	V	
Collector current	$T_C = 25^\circ\text{C}$	I_C	100	A
	$T_C = 100^\circ\text{C}$	I_C	50	A
Junction temperature	T_j	175 ^{Note1}	$^\circ\text{C}$	

Notes: 1. Please use this device in the thermal conditions where the junction temperature does not exceed 175°C.
 IGBT Application Note is disclosed about reliability test and application condition up to $T_j = 175^\circ\text{C}$.

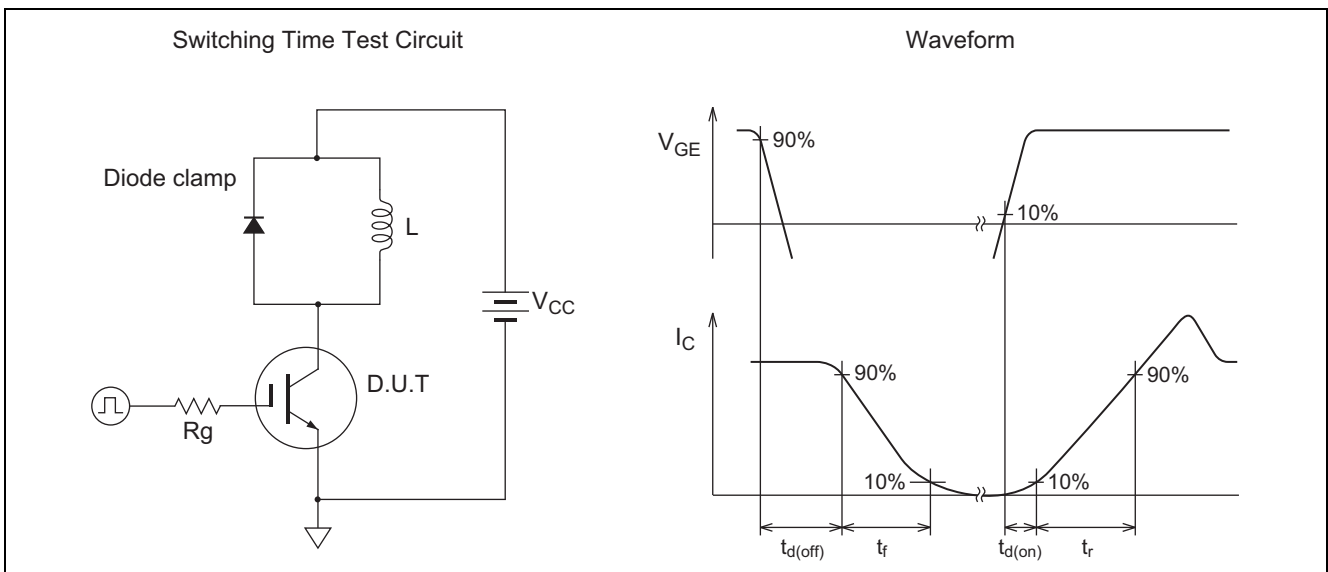
Electrical Characteristics (These data are actual measurement values in an evaluation package.)(T_c = 25°C unless otherwise noted)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	—	—	1	μA	V _{CE} = 1250 V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	—	—	±1	μA	V _{GE} = ±30 V, V _{CE} = 0
Gate to emitter cutoff voltage	V _{GE(off)}	5.0	—	6.8	V	V _{CE} = 10 V, I _C = 1.7 mA
Collector to emitter saturation voltage	V _{CE(sat)}	—	1.80	2.25	V	I _C = 50 A, V _{GE} = 15 V ^{Note2}
Input capacitance	C _{ies}	—	5.3	—	nF	V _{CE} = 25 V
Output capacitance	C _{oes}	—	0.16	—	nF	V _{GE} = 0
Reveres transfer capacitance	C _{res}	—	0.12	—	nF	f = 1 MHz
Total gate charge	Q _g	—	290	—	nC	V _{GE} = 15 V
Gate to emitter charge	Q _{ge}	—	50	—	nC	V _{CE} = 600 V
Gate to collector charge	Q _{gc}	—	155	—	nC	I _C = 50 A
Switching time ^{Note3}	t _{d(on)}	—	30	—	ns	V _{CC} = 600 V
	t _r	—	30	—	ns	I _C = 50 A
	t _{d(off)}	—	290	—	ns	V _{GE} = ±15 V
	t _f	—	160	—	ns	R _g = 10 Ω, T _c = 150 °C Inductive load
Short circuit withstand time ^{Note4}	t _{sc}	10	—	—	μs	V _{CC} ≤ 720 V, V _{GE} = 15 V T _c = 150 °C

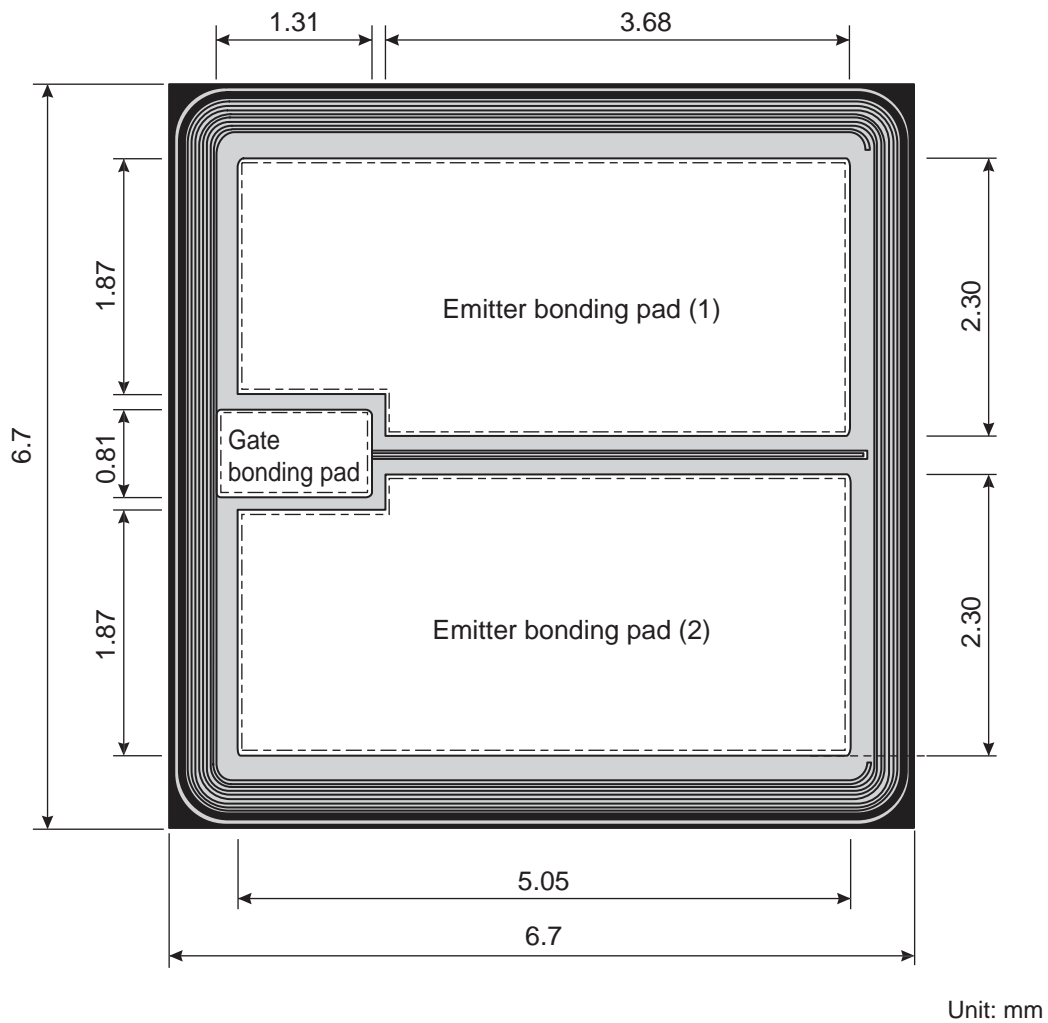
Notes: 2. Pulse test.

3. Switching time test circuit and waveform are shown below.

4. Verified by design.



Die Dimension



Unit: mm

Note 1.

Illustration	Definition
Part of white	Al pattern
Part of dotted line	Bonding area
Part of gray	Final passivation

Note 2. The back of the chip is processed with Au evaporation.

Note 3. Recognition, target and any other patterns which are not related to IGBT operation, may be changed without notice.

Ordering Information

Orderable Part Number	Shipment form
RJP1CS04DWA-80#W0	Unsaun wafer
RJP1CS04DWS-80#W0	Saun wafer

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Renesas Electronics America Inc.
2801 Scott Boulevard Santa Clara, CA 95050-2549, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3
Tel: +1-905-237-2004

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 1709, Quantum Plaza, No.27 ZhichunLu Haidian District, Beijing 100191, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tel: +86-21-2226-0888, Fax: +86-21-2226-0899

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2265-8688, Fax: +852-2886-9022

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan
Tel: +886-2-8175-9600, Fax: +886-2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jin Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd.
No.777C, 100 Feet Road, HAL II Stage, Indiranagar, Bangalore, India
Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd.
12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141